

TM
AF



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Geum-Jong BAE, et al

Art Unit: 2814

Serial No. 10/659,384
(Division of Serial No. 10/274,035)

Examiner: H.V. Pham

Filed: September 11, 2003

Confirmation No. 3795

For: MOS TRANSISTOR HAVING A T-SHAPED
GATE ELECTRODE AND METHOD FOR
FABRICATING THE SAME

Attorney Docket No. 239/169 DIV

AMENDMENT UNDER 37 C.F.R. § 1.116

Mail Stop: Box AF
Commissioner for Patents
United States Patent and Trademark Office
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Alexandria, VA 22313-1450

Sir:

INTRODUCTORY COMMENTS

In response to the Office Action Made Final dated December 8, 2005, the following amendments and remarks are respectfully submitted in connection with the above-identified application:

Amendments to the Claims are reflected in a listing of claims, which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.